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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	56340
Total RAM Bits	1869824
Number of I/O	200
Number of Gates	-
Voltage - Supply	1.14V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	325-TFBGA, FCBGA
Supplier Device Package	325-FCBGA (11x11)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/m2gl050t-1fcsg325

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- Added Table 244, page 94 and Table 256, page 99 (SAR 73971).
- Updated the SerDes Electrical and Timing AC and DC Characteristics, page 121 (SAR 71171).
- Added the DEVRST_N Characteristics, page 116 (SAR 64100, 72103).
- Added Table 298, page 122 (SAR 71897).
- Updated Table 25, page 22, Table 26, page 23, and Table 27, page 23 (SAR 74570).
- Added 060 devices in Table 277, page 107, Table 278, page 108, and Table 279, page 108 (SAR 57898).
- Updated duty cycle parameter of crystal in Table 280, page 109 and Table 281, page 109 (SAR 57898).
- Added 32 KHz mode PLL acquisition time in Table 282, page 110 (SAR 68281).
- Updated Table 293, page 119 for 060 devices (SAR 57828).
- Updated Table 297, page 122 for CID value (SAR 70878).

1.4 Revision 8.0

The following is a summary of the changes in revision 8.0 of this document.

- Updated Table 11, page 12 (SAR 69218).
- Updated Table 12, page 13 (SAR 69218).
- Updated Table 283, page 111 (SAR 69000).

1.5 Revision 7.0

The following is a summary of the changes in revision 7.0 of this document.

- Updated Table 1, page 4 (SAR 68620).

1.6 Revision 6.0

The following is a summary of the changes in revision 6.0 of this document.

- Updated Table 5, page 7 (SAR 65949).
- Updated Table 9, page 10 (SAR 62995).
- Updated Table 123, page 47 and Table 133, page 49 (SAR 67210).
- Added Embedded NVM (eNVM) Characteristics, page 104 (SAR 52509).
- Updated Table 277, page 107 (SAR 64855).
- Updated Table 282, page 110 (SAR 65958 and SAR 56666).
- Added DDR Memory Interface Characteristics, page 120 (SAR 66223).
- Added SFP Transceiver Characteristics, page 120 (SAR 63105).
- Updated Table 302, page 123 and Table 309, page 129 (SAR 66314).

1.7 Revision 5.0

The following is a summary of the changes in revision 5.0 of this document.

- Updated Table 1, page 4.
- Updated Table 4, page 6 for T_J symbol information.
- Updated Table 5, page 7 (SAR 63109).
- Updated Table 9, page 10.
- Updated Table 282, page 110 (SAR 62012).
- Added Table 290, page 116 (SAR 64100).
- Added Table 306, page 128, Table 307, page 128 (SAR 50424).

1.8 Revision 4.0

The following is a summary of the changes in revision 4.0 of this document.

- Updated Table 1, page 4. Changed the Status of 090 devices to "Production" (SAR 62750).
- Updated Figure 10, page 70. Removed inverter bubble from DDR_IN latch (SAR 61418).
- Updated SerDes Electrical and Timing AC and DC Characteristics, page 121 (SAR 62836).

1.9 Revision 3.0

In revision 3.0 of this document, the Theta B/C columns and FCS325 package was updated. For more information, see Table 9, page 10 (SAR 62002).

1.10 Revision 2.0

The following is a summary of the changes in revision 2.0 of this document.

- Table 1, page 4 was updated (SAR 59056).
- Table 7, page 8 temperature and data retention information was updated SAR (61363).
- Storage Operating Table was updated and split into three tables – Table 5, page 7, Table 7, page 8 (SAR 58725).
- Updated Theta B/C columns and FCS325 package in Table 9, page 10 (SAR 62002).
- Added 090-FCS325 thermal resistance to Table 9, page 10 (SAR 59384).
- TQ144 package was added to Table 9, page 10 (SAR 57708).
- Added PLL jitter data for the VF400 package (SAR 53162).
- Added Additional Worst Case IDD to Table 11, page 12 and Table 12, page 13 (SAR 59077).
- Table 13, page 13, Table 14, page 13, and Table 15, page 14 were added to verify Inrush currents (SAR 56348).
- Table 18, page 19 and Table 21, page 20 – I/O speeds were replaced.
- Max speed was changed in Table 41, page 26 (SAR 57221) and in Table 52, page 29 (SAR 57113).
- Minimum and Maximum DC/AC Input and Output Levels Specification, page 29 and Table 49, page 29–Table 57, page 31 were added.
- Added Cload to Table 89, page 39 (SAR 56238).
- Removed "Rs" information in DDR Timing Measurement Table 123, page 47, Table 133, page 49, and Table 144, page 52.
- Updated drive programming for M/B-LVDS outputs (SAR 58154).
- Added an inverter bubble to DDR_IN latch in Figure 10, page 70 (SAR 61418).
- QF waveform in Figure 11, page 71 was updated (SAR 59816).
- uSRAM Write Clock minimum values were updated in Table 237, page 86–Table 243, page 93 (SAR 55236).
- Fixed typo in the 32 kHz Crystal (XTAL) oscillator accuracy data section (SAR 59669).
- The "On-Chip Oscillator" section was split, and the Embedded NVM (eNVM) Characteristics, page 104 was added. Table 277, page 107–Table 281, page 109 were revised.(SARs 57898 and 59669).
- PLL VCP Frequency and conditions were added to Table 282, page 110 (SAR 57416).
- Fixed typo for PLL jitter data in the 100-400 MHz range (SAR 60727).
- Updated FCCC information in Table 282, page 110 and Table 283, page 111 (SAR 60799).
- Device 025 specifications were added to Table 283, page 111 (SAR 51625).
- JTAG Table 284, page 112 was replaced (SAR 51188).
- Flash*Freeze Table 293, page 119 was replaced (SAR 57828).
- Added support for HCSL I/O Standard for SERDES reference clocks in Table 300, page 123 and Table 301, page 123 (SAR 50748).
- Tir and Tif parameters were added to Table 303, page 124 (SAR 52203).
- Speed grade consistency was fixed in tables throughout the datasheet (SAR 50722).
- Added jitter attenuation information (SAR 59405).

1.11 Revision 1.0

The following is a summary of the changes in revision 1.0 of this document.

- The IGLOO2 v2 and the SmartFusion2 v5 datasheets are combined into this single product family datasheet.

